BUJ100LR

NPN power transistor

Rev. 02 — 29 July 2010

Product data sheet

1. Product profile

1.1 General description

High voltage, high speed, planar passivated NPN power switching transistor in a SOT54 (TO-92) 3 leads plastic package.

1.2 Features and benefits

Fast switching

1.3 Applications

- Compact fluorescent lamps (CFL)
- Electronic lighting ballasts

1.4 Quick reference data

- High voltage capability of 700 V
- Inverters
- Off-line self-oscillating power supplies

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _C	collector current	DC; see Figure 2	-	-	1	А
P _{tot}	total power dissipation	T _{lead} ≤ 25 °C; see <u>Figure 1</u>	-	-	2.1	W
V _{CESM}	collector-emitter peak voltage	$V_{BE} = 0 V$	-	-	700	V
Static cha	aracteristics					
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_C = 0.8 \text{ A};$ $T_{lead} = 25 \text{ °C}; \text{ see } \underline{Figure 8};$ see $\underline{Figure 9}$	5	7.5	20	



2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		
2	С	collector		C
3	E	emitter		B – E sym123
			SOT54 (TO-92)	

3. Ordering information

Table 3. Orderin	g information		
Type number	Package		
	Name	Description	Version
BUJ100LR	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

4. Limiting values

Table 4.Limiting values

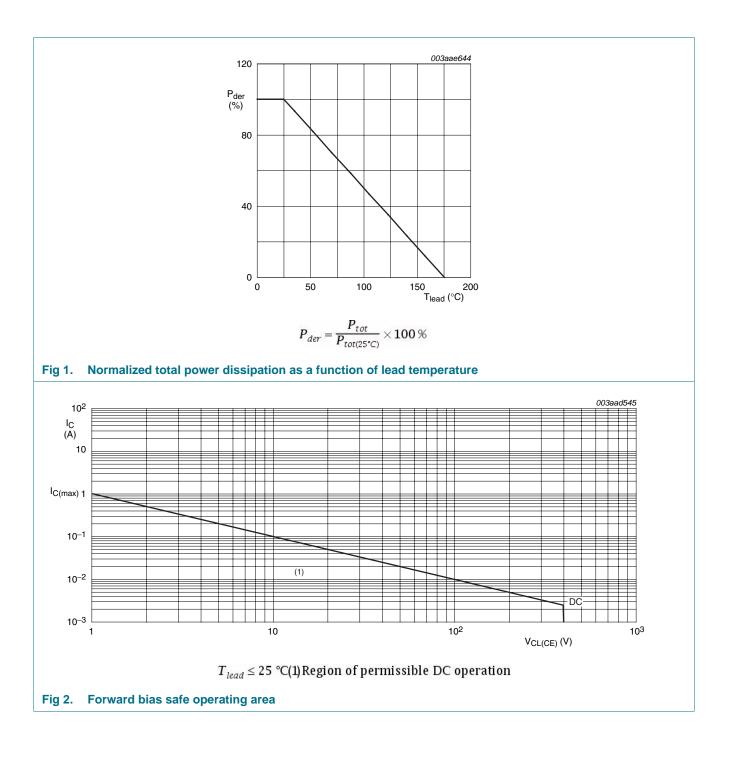
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CESM}	collector-emitter peak voltage	$V_{BE} = 0 V$	-	700	V
V _{CBO}	collector-base voltage	I _E = 0 A	-	700	V
V _{CEO}	collector-emitter voltage	I _B = 0 A	-	400	V
I _C	collector current	DC; see Figure 2	-	1	А
I _{CM}	peak collector current		-	2	А
I _B	base current	DC	-	0.5	А
I _{BM}	peak base current		-	1	А
P _{tot}	total power dissipation	T _{lead} ≤ 25 °C; see <u>Figure 1</u>	-	2.1	W
T _{stg}	storage temperature		-65	150	°C
Tj	junction temperature		-	150	°C
V _{EBO}	emitter-base voltage	$I_{C} = 0 \text{ A}$; I(Emitter) = 10 mA	-	9	V

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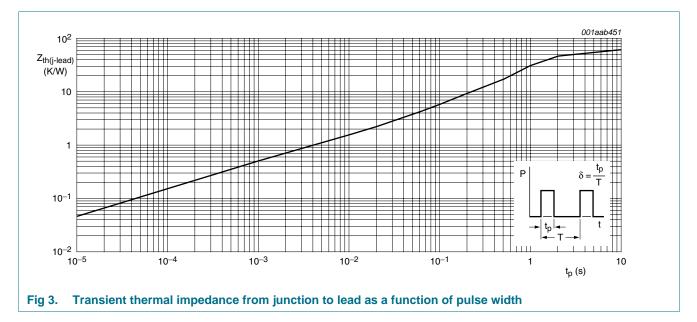
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5. Thermal characteristics

Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	see Figure 3	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	printed-circuit board mounted; lead length 4 mm	-	150	-	K/W

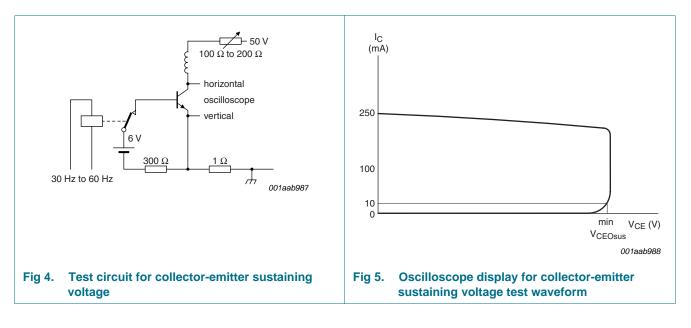


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6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{CES}	collector-emitter cut-off current	V_{BE} = 0 V; V_{CE} = 700 V; T_j = 125 °C	-	-	5	mA
I _{EBO}	emitter-base cut-off current	V_{EB} = 9 V; I _C = 0 A; T _{lead} = 25 °C	-	-	1	mA
V _{CEOsus}	collector-emitter sustaining voltage	$I_B = 0 A$; $I_C = 1 mA$; $L_C = 25 mH$; $T_{lead} = 25 \text{ °C}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	400	-	-	V
OLGAI	collector-emitter saturation voltage	I_{C} = 0.25 A; I_{B} = 50 mA; T_{lead} = 25 °C; see <u>Figure 6</u>	-	0.2	0.5	V
		$I_C = 0.5 \text{ A}; I_B = 125 \text{ mA}; T_{\text{lead}} = 25 \text{ °C};$ see Figure 6	-	0.3	1	V
		I_{C} = 0.75 A; I_{B} = 250 mA; T_{lead} = 25 °C; see <u>Figure 6</u>	-	0.4	1.5	V
V _{BEsat}	base-emitter saturation voltage	I_{C} = 0.25 A; I_{B} = 50 mA; T_{lead} = 25 °C; see <u>Figure 7</u>	-	-	1	V
		I_{C} = 0.5 A; I_{B} = 125 mA; T_{lead} = 25 °C; see Figure 7	-	-	1.2	V
h _{FE}	DC current gain	I_{C} = 0.5 mA; V_{CE} = 2 V; T_{lead} = 25 °C	12	-	-	
		$I_{C} = 0.4 \text{ A}; V_{CE} = 5 \text{ V}; T_{lead} = 25 \text{ °C};$ see <u>Figure 8</u> ; see <u>Figure 9</u>	10	-	30	
		$I_C = 0.8 \text{ A}; V_{CE} = 5 \text{ V}; T_{lead} = 25 \text{ °C};$ see <u>Figure 8</u> ; see <u>Figure 9</u>	5	7.5	20	
Dynamic	characteristics					
t _f	fall time	I _C = 1 A; I _{Bon} = 200 mA; V _{BB} = -5 V;	-	80	-	ns

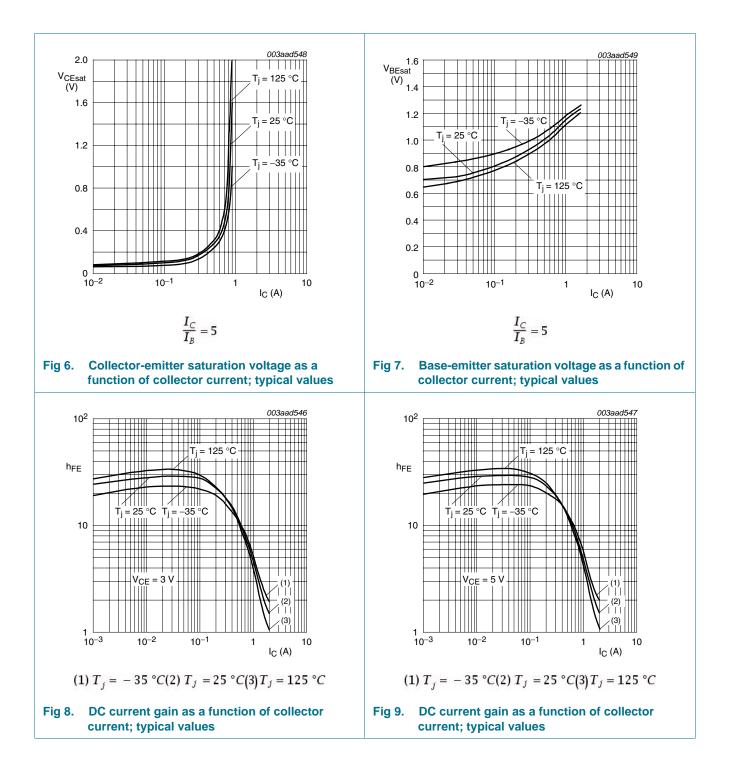
fall time $I_C = 1 A$; $I_{Bon} = 200 mA$; $V_{BB} = -5 V$; - 80 - ns $L_B = 1 \mu H$; $T_{lead} = 25 °C$; inductive load; see Figure 10; see Figure 11



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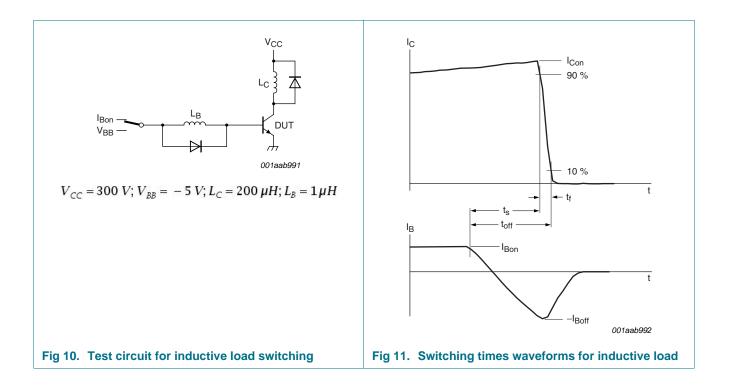
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7. Package outline

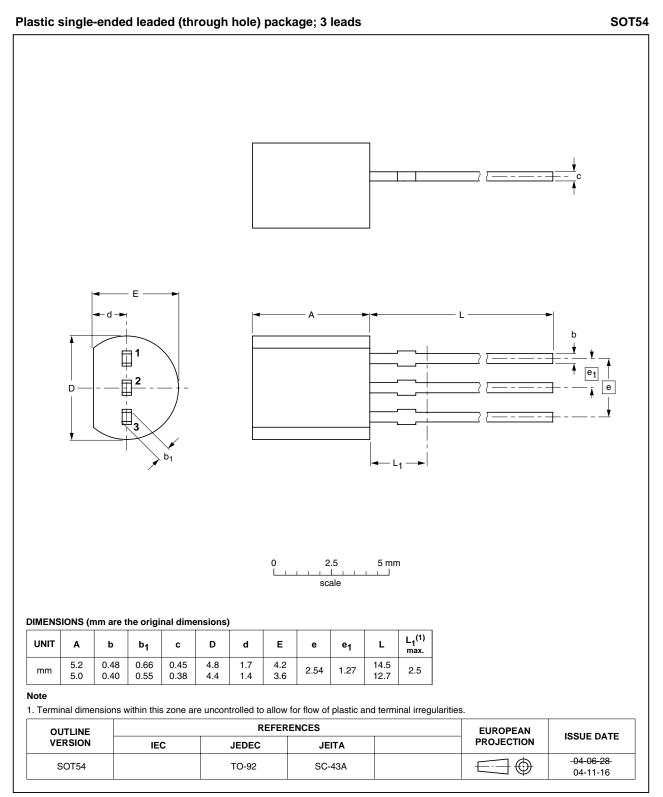


Fig 12. Package outline SOT54 (TO-92)

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8. Revision history

Table 7.Revision	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BUJ100LR v.2	20100729	Product data sheet	-	BUJ100LR v.1
Modifications:	 Various chang 	es to content.		
BUJ100LR v.1	20090812	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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